## **Changes from May 2008 meeting:**

1. The setup was updated to reflect all types of Midspan implementation (transformers or autotransformers) in order to ensure that the device is tested under DC bias current.

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## 33.4.8.2 Midspan signal path requirements

An Alternative A Midspan PSE transfer function gain shall be greater than expressed by equation 33-14 for the frequency range f, at the pins of the PI used as 100BASETX transmit pins:

$$\begin{cases} -c + 37.5 \cdot LOG_{10} \left( \frac{a \cdot f}{\sqrt{1 + b \cdot f^2}} \right) \end{cases}$$

$$a = 22.40$$

$$b = 520.5$$

$$c = 0.1000$$

$$0.1MHz \le f < 1MHz$$

where

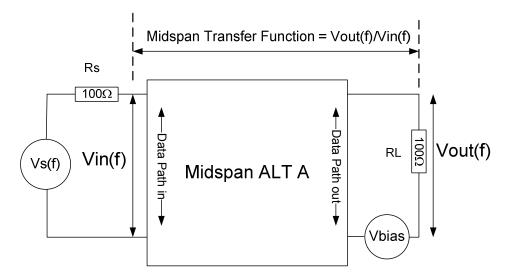
f is the frequency expressed in MHz.

Additionally, the requirements will be met with a DC bias current, Ibias between 0 mA and  $\{0 + 0.5*$ Iunb mA $\}$  (Iunb is defined in Table 33–9).

## 33.4.8.2.1 Alternative A Midspan PSE Compliance test setup

Compliance testing shall be performed by applying test signal to the Midspan PSE signal input with a source impedance of  $100 \Omega \pm 1 \%$ . The Midspan PSE signal input and output may be connected to a 0.5 m max length of CAT5 cable, terminated with  $100 \Omega \pm 1\%$ .

The transfer function shall be measured from the output termination to the signal input. See figure 33-24-1.



- Vin(f) is the Sine wave signal to be used to measure the Midspan TF.
- Vbias is the DC offset voltage to be applied in series to RL in order to generate Ibias.
- Vout (f) is the Midspan response to Vin(f)

Figure 33-24-1. Measurement Setup For Alternative A Midspan PSE Transfer Function